



FFB20UP30DN

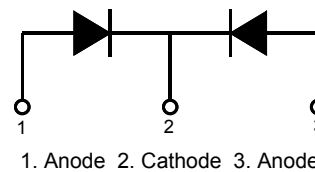
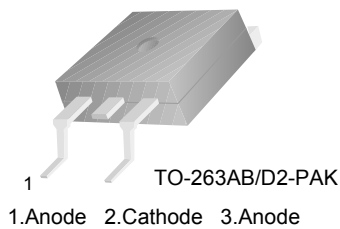
Ultrafast Recovery Power Rectifier

Features

- Ultrafast with Soft Recovery : < 45ns(@ $I_F=10A$)
- High Reverse Voltage : $V_{RRM} = 300V$
- Avalanche Energy Rated
- Planar Construction

Applications

- General purpose
- Switching Mode Power Supply
- Free-wheeling diode for motor application
- Power switching circuits



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	300	V
V_{RWM}	Working Peak Reverse Voltage	300	V
V_R	DC Blocking Voltage	300	V
$I_{F(AV)}$	Average Rectified Forward Current Rating for each diode $I_{F(AV)}/2$ @ $T_C = 130^\circ C$	20	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	180	A
T_J, T_{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C

Thermal Characteristics

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	2.0	°C/W

Package Marking and Ordering Information

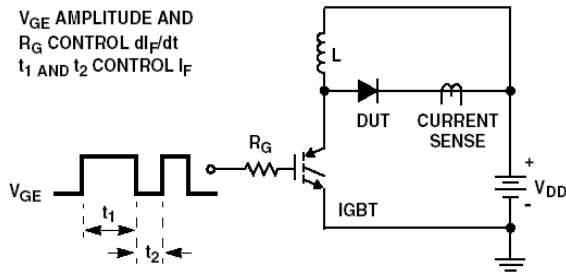
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F20UP30DN	FFB20UP30DNTM	TO-263AB/D2-PAK	13" Dia	-	800

Electrical Characteristics (per diode) $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Min.	Typ.	Max.	Units	
V_{FM}^*	$I_F = 10\text{A}$ $I_F = 10\text{A}$	$T_C = 25^\circ\text{C}$	-	-	1.3	V
		$T_C = 150^\circ\text{C}$	-	-	1.2	V
I_{RM}^*	$V_R = 300\text{V}$ $V_R = 300\text{V}$	$T_C = 25^\circ\text{C}$	-	-	1	μA
		$T_C = 150^\circ\text{C}$	-	-	500	μA
t_{rr}	$I_F = 0.5\text{A}, I_{rr} = 1\text{A}, V_{CC} = 30\text{V}$ $I_F = 1\text{A}, di/dt = 100\text{A}/\mu\text{s}, V_{CC} = 30\text{V}$ $I_F = 10\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_{CC} = 195\text{V}$	$T_C = 25^\circ\text{C}$	-	-	30	ns
		$T_C = 25^\circ\text{C}$	-	-	35	ns
		$T_C = 25^\circ\text{C}$	-	-	45	ns
t_a t_b Q_{rr}	$I_F = 10\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_{CC} = 195\text{V}$	$T_C = 25^\circ\text{C}$	-	11	-	ns
		$T_C = 25^\circ\text{C}$	-	13	-	ns
		$T_C = 25^\circ\text{C}$	-	20	-	nC
W_{AVL}	Avalanche Energy ($L = 20\text{mH}$)	20	-	-	mJ	

* Pulse Test: Pulse Width=300 μs , Duty Cycle=2%

Test Circuit and Waveforms

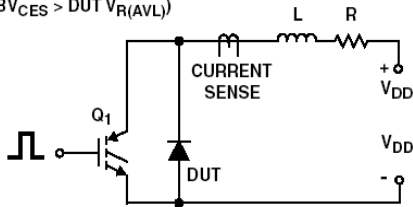


t_{rr} TEST CIRCUIT

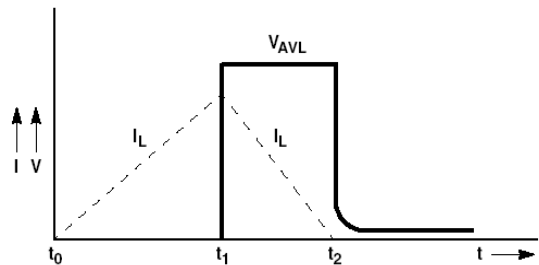


t_{rr} WAVEFORMS AND DEFINITIONS

$I_{MAX} = 1\text{A}$
 $L = 40\text{mH}$
 $R < 0.1\Omega$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
 $Q_1 = \text{IGBT (}BV_{CES} > \text{DUT } V_{R(AVL)})$



AVALANCHE ENERGY TEST CIRCUIT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop

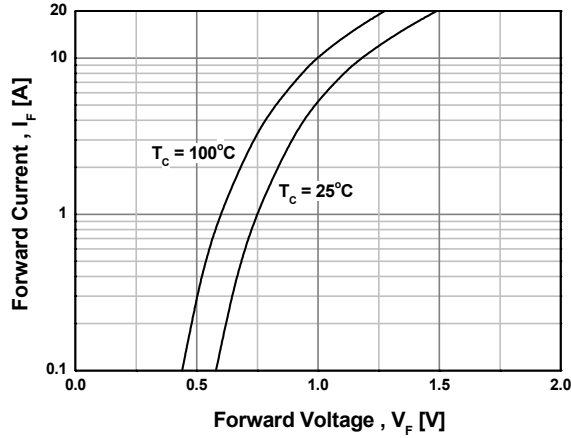


Figure 2. Typical Reverse Current

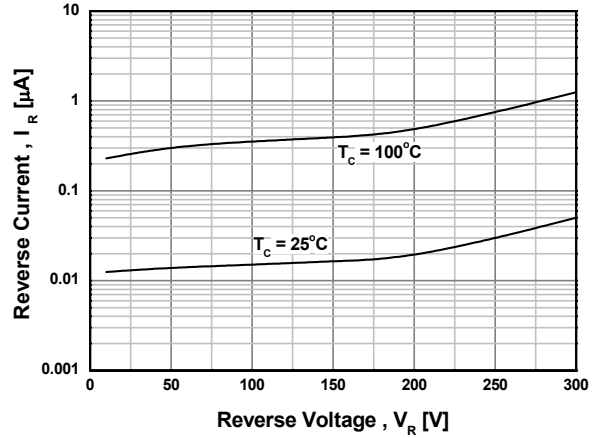


Figure 3. Typical Junction Capacitance

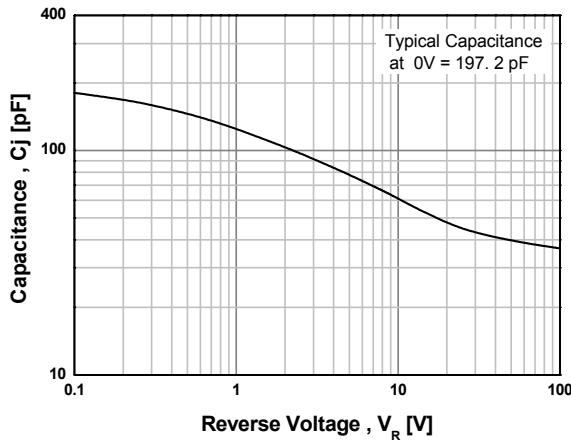


Figure 4. Typical Reverse Recovery Time

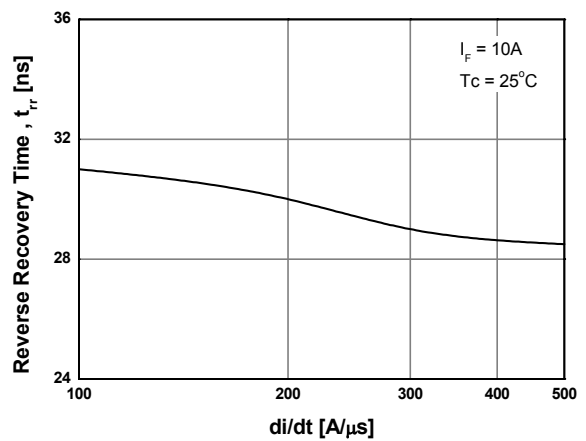


Figure 5. Typical Reverse Recovery Current

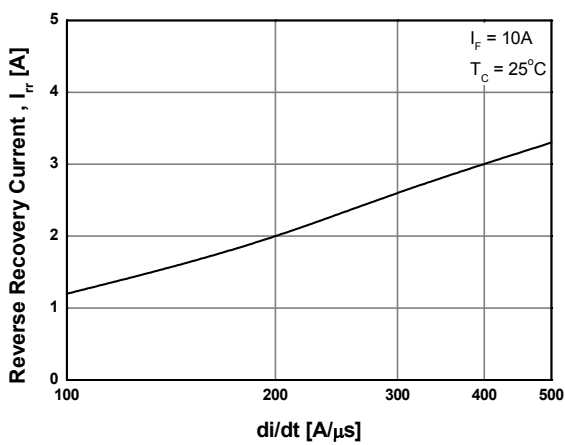
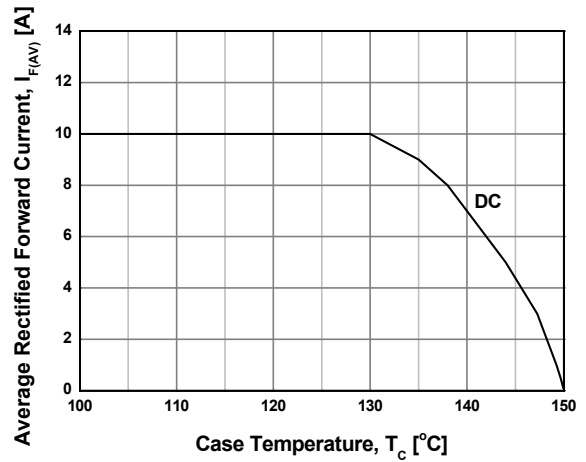
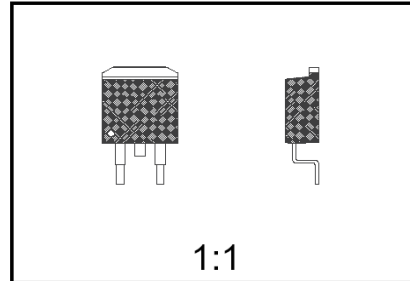
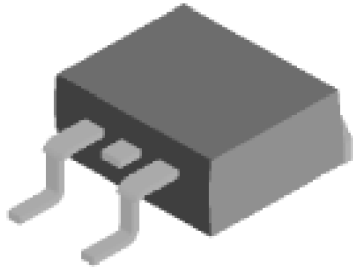


Figure 6. Forward Current Deration Curve



Package Dimensions

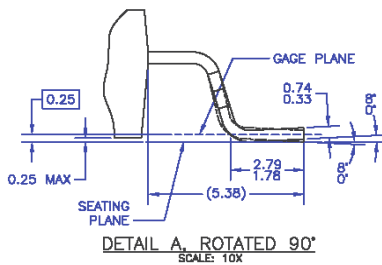
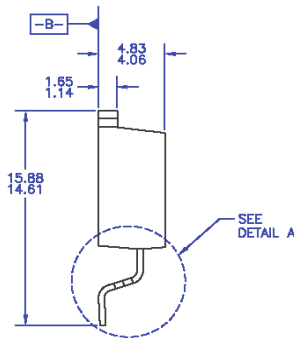
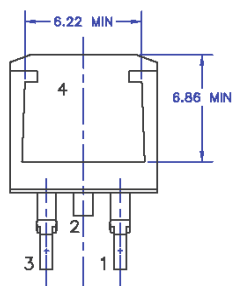
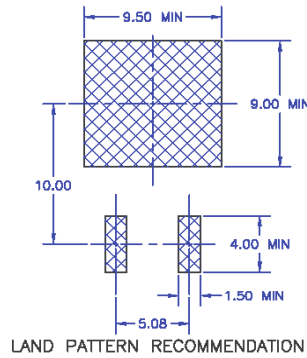
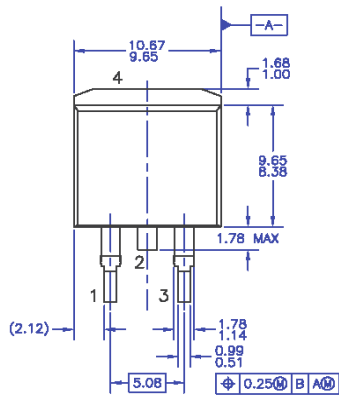
TO-263AB/D²-PAK



Scale 1:1 on letter size paper

Dimensions shown below are in:
millimeters

Part Weight per unit (gram): 1.4378



- NOTES: UNLESS OTHERWISE SPECIFIED
- A) ALL DIMENSIONS ARE IN MILLIMETERS.
 - B) REFERENCE JEDEC, TO-263, ISSUE D, VARIATION AB, DATED JULY 2003.
 - C) DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1982.
 - D) LOCATION OF THE PIN HOLE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE).
 - E) PRESENCE OF TRIMMED CENTER LEAD IS OPTIONAL.

TO263A02REVD

Dimensions in Millimeters

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